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## NCE N-Channel Enhancement Mode Power MOSFET

## **Description**

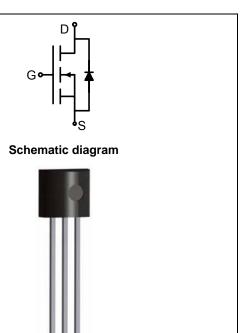
The NCE0106Z uses advanced trench technology and design to provide excellent  $R_{DS(ON)}$  with low gate charge. It can be used in a wide variety of applications.

#### **General Features**

- $V_{DS}$  = 100V, $I_D$  = 6A  $R_{DS(ON)}$  < 140mΩ @  $V_{GS}$ =10V (Typ:110mΩ)
- High density cell design for ultra low Rdson
- Fully characterized avalanche voltage and current
- Excellent package for good heat dissipation

## **Application**

- Power switching application
- Hard switched and high frequency circuits
- Uninterruptible power supply



TO-92 view

#### **Package Marking and Ordering Information**

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
0106Z	NCE0106Z	TO-92	-	-	-

Absolute Maximum Ratings (T<sub>A</sub>=25 ℃unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V <sub>DS</sub>	100	V
Gate-Source Voltage	V <sub>GS</sub>	±20	V
Drain Current-Continuous	I <sub>D</sub>	6	Α
Drain Current-Pulsed (Note 1)	I <sub>DM</sub>	24	Α
Maximum Power Dissipation	P <sub>D</sub>	3	W
Operating Junction and Storage Temperature Range	$T_{J}$ , $T_{STG}$	-55 To 150	$^{\circ}\!$

#### **Thermal Characteristic**

Thermal Resistance, Junction-to-Ambient (Note 2)	$R_{ heta JA}$	41.7	°C/W
, and the second		1	1

# **Electrical Characteristics (T<sub>A</sub>=25**°C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics						
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V I <sub>D</sub> =250μA	100	110	-	V
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =100V,V <sub>GS</sub> =0V	-	-	1	μΑ



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# NCE0106Z

Gate-Body Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> =±20V,V <sub>DS</sub> =0V		-	±100	nA	
On Characteristics (Note 3)							
Gate Threshold Voltage	V <sub>GS(th)</sub>	V <sub>DS</sub> =V <sub>GS</sub> ,I <sub>D</sub> =250μA	1.2	1.8	2.5	V	
Drain-Source On-State Resistance	R <sub>DS(ON)</sub>	V <sub>GS</sub> =10V, I <sub>D</sub> =5A	-	110	140	mΩ	
Forward Transconductance	<b>g</b> FS	V <sub>DS</sub> =5V,I <sub>D</sub> =2.9A	-	8	-	S	
Dynamic Characteristics (Note4)	·						
Input Capacitance	C <sub>lss</sub>	\/ -25\/\/ -0\/	-	690	-	PF	
Output Capacitance	C <sub>oss</sub>	- V <sub>DS</sub> =25V,V <sub>GS</sub> =0V, - F=1.0MHz	-	120	-	PF	
Reverse Transfer Capacitance	C <sub>rss</sub>	F-1.UIVITIZ	-	90	-	PF	
Switching Characteristics (Note 4)	•						
Turn-on Delay Time	t <sub>d(on)</sub>		-	11	-	nS	
Turn-on Rise Time	t <sub>r</sub>	$V_{DD}$ =30 $V$ , $I_D$ =2 $A$ , $R_L$ =15 $\Omega$	-	7.4	-	nS	
Turn-Off Delay Time	$t_{d(off)}$	$V_{GS}$ =10 $V$ , $R_{G}$ =2.5 $\Omega$	-	35	-	nS	
Turn-Off Fall Time	t <sub>f</sub>		-	9.1	-	nS	
Total Gate Charge	$Q_g$	\/ -20\/   -24	-	15.5		nC	
Gate-Source Charge	$Q_{gs}$	$V_{DS}=30V,I_{D}=3A,$ $V_{GS}=10V$	-	3.2	-	nC	
Gate-Drain Charge	$Q_{gd}$	V <sub>GS</sub> -10V	-	4.7	-	nC	
Drain-Source Diode Characteristics							
Diode Forward Voltage (Note 3)	$V_{SD}$	V <sub>GS</sub> =0V,I <sub>S</sub> =6A	-	-	1.2	V	
Diode Forward Current (Note 2)	Is		-	-	6	Α	

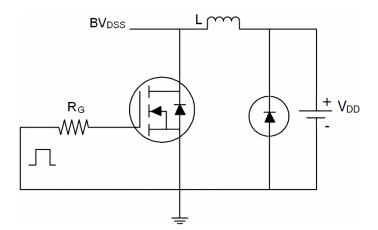
# Notes:

- 1. Repetitive Rating: Pulse width limited by maximum junction temperature.
- 2. Surface Mounted on FR4 Board, t ≤ 10 sec.
- 3. Pulse Test: Pulse Width  $\leq$  300 $\mu$ s, Duty Cycle  $\leq$  2%.
- $\textbf{4.} \ \textbf{Guaranteed by design}, \ \textbf{not subject to production}$

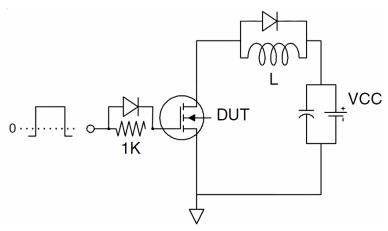


# **Test Circuit**

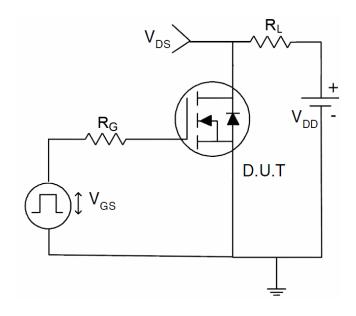
# 1) E<sub>AS</sub> test circuit



# 2) Gate charge test circuit



#### 3) Switch Time Test Circuit



## **Typical Electrical and Thermal Characteristics (curves)**

Figure 1. Source-Drain Diode Forward Voltage

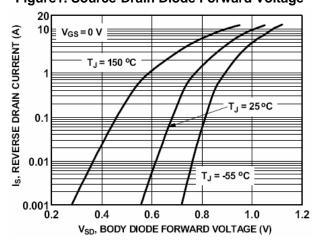


Figure3. Output characteristics

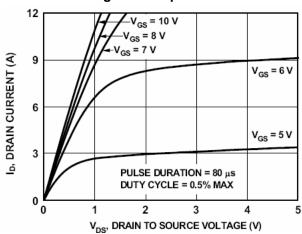


Figure5. Static drain-source on resistance

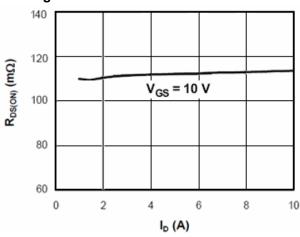


Figure 2. Safe operating area

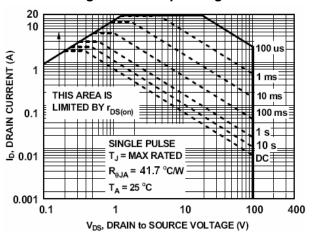


Figure 4. Transfer characteristics

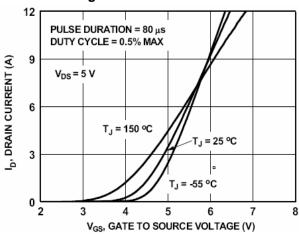


Figure 6. R<sub>DS(ON)</sub> vs Junction Temperature

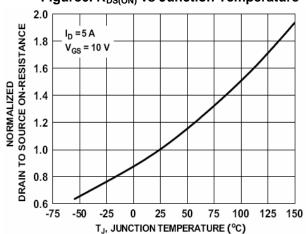


Figure 7. BV<sub>DSS</sub> vs Junction Temperature

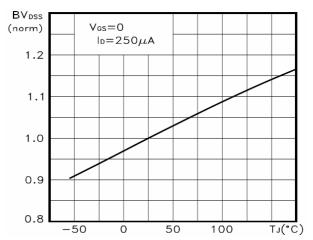


Figure 8.  $V_{\text{GS(th)}}$  vs Junction Temperature

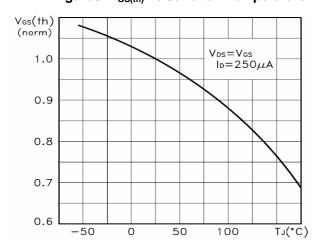


Figure 9. Gate charge waveforms

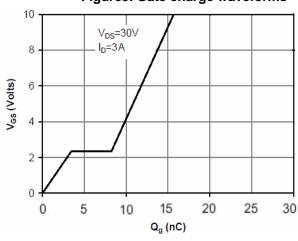
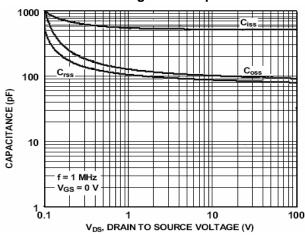


Figure 10. Capacitance



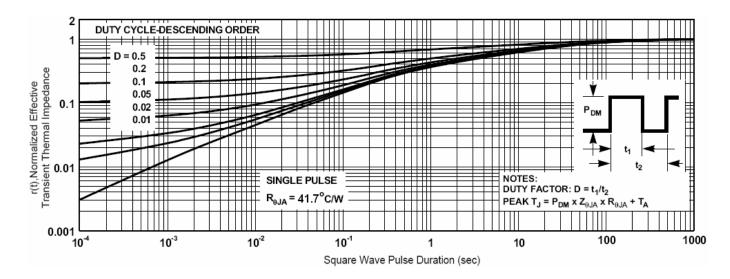
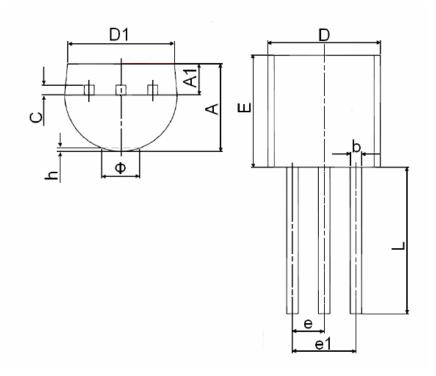


Figure 11. Normalized Maximum Transient Thermal Impedance

# **TO-92 Package Information**



Symbol	Dimensions	In Millimeters	Dimensions In Inches			
Syllibol	Min	Max	Min	Max		
Α	3.300	3.700	0.130	0.146		
A1	1.100	1.400	0.043	0.055		
b	0.380	0.550	0.015	0.022		
С	0.360	0.510	0.014	0.020		
D	4.400	4.700	0.173	0.185		
D1	3.430		0.135			
E	4.300	4.700	0.169	0.185		
е	1.270	TYP	0.050 TYP			
e1	2.440	2.640	0.096	0.104		
L	14.100	14.500	0.555	0.571		
Ф		1.600		0.063		
h	0.000	0.380	0.000	0.015		

#### **Notes**

- 1. All dimensions are in millimeters.
- 2. Tolerance ±0.10mm (4 mil) unless otherwise specified
- 3. Package body sizes exclude mold flash and gate burrs. Mold flash at the non-lead sides should be less than 5 mils.
- 4. Dimension L is measured in gauge plane.
- 5. Controlling dimension is millimeter, converted inch dimensions are not necessarily exact.

**Pb-Free Product** 

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